Fabrication of Hierarchically Porous Reduced Graphene Oxide/SnIn₄S₈ Composites by a Low-Temperature Co-Precipitation Strategy and Their Excellent Visible-Light Photocatalytic Mineralization Performance

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Abstract: Hierarchically porous reduced graphene oxide/SnIn₄S₈ (RGO/SnIn₄S₈) composites with visible-light response and strong mineralization ability were first successfully prepared by a facile low-temperature co-precipitation method, and were characterized by X ray diffraction (XRD), scanning electron microscope (SEM), Brunauer-Emmet-Teller (BET), UV-Visible spectrophotometer (UV-Vis), Raman spectra and Photoluminescence (PL) techniques. RGO/SnIn₄S₈ composite exhibits strong absorption in UV and visible-light range. The optimized 5% RGO/SnIn₄S₈ possesses the optimal photocatalytic degradation efficiency and the best mineralization performance with complete degradation of Rhodamine B (RhB) within 70 min and 73.17% mineralization yield within 160 min under visible-light irradiation, which is much higher than that of pure SnIn₄S₈. The main reactive species, which play crucial roles in the degradation and mineralization of RhB, follow the order of \( h^+ > \cdot O_2^- > \cdot OH \). The intermediate products of RhB degradation were analyzed by using high performance liquid chromatography-tandem mass spectrometry (HPLC-MS), and the possible degradation pathways and mechanism were proposed. Moreover, 5% RGO/SnIn₄S₈ exhibits excellent reusability and stability without an obvious decrease in photocatalytic activity after four consecutive photocatalytic degradation-regeneration experiments.

Keywords: SnIn₄S₈; reduced graphene oxide; composite; visible light; mineralization

1. Introduction

Water pollution has attracted public attention due to the environmental and health risks [1–5]. Dye contamination has become a major factor that contributes to water quality deterioration, and poses a potential hazard to living organisms due to the toxic, carcinogenic and mutagenic properties of dyes and their by-products [6–10]. Hence, the removal of organic dye pollutants from the wastewater becomes very essential. Up to now, several methods have been adopted to remove dyes from wastewater, including adsorption, coagulation, biological treatment, electrochemical treatment and heterogeneous photocatalytic oxidation technology [11–15]. Among these methods, heterogeneous photocatalytic oxidation technology is one of the best available technologies for dye removal from
To date, TiO$_2$ is regarded as one of the most promising semiconductor photocatalysts for degrading organic compounds because of its high photocatalytic activity, low cost, non-toxicity, chemical stability, and biocompatibility [16–19]. However, TiO$_2$ has a large band gap (3.2 eV for anatase and 3.0 eV for rutile) and can only respond to ultraviolet (UV) irradiation, which restricts its practical application [20–23]. Moreover, a number of intermediates are usually produced during the TiO$_2$ photocatalytic degradation process, and are difficult to be further degraded. Some intermediates are even more toxic than their parental pollutants, thus it is urgent to develop new visible-light-responsive photocatalysts that can mineralize pollutants to inorganic products within a short reaction time.

Ternary chalcogenide compounds have attracted much concern due to their narrow band gap and high stability. Stannum indium sulfide (SnIn$_4$S$_8$) is a representative ternary chalcogenide semiconductor, and exhibits potential application in photocatalysis [24–26]. However, a single SnIn$_4$S$_8$ semiconductor usually has a small specific surface area and fast electron–hole recombination, which limit its photocatalytic efficiency. Hence, further modification of SnIn$_4$S$_8$ photocatalysts for high photon quantum efficiency is indispensable.

Reduced graphene oxide (RGO) has large specific surface area, superior electrical conductivity, high carrier mobility, and excellent mechanical properties, and is usually used as a good support to enhance the photocatalytic activities of some photocatalysts [27–31]. Herein, we first report a facile and simple synthesis of reduced graphene oxide/SnIn$_4$S$_8$ (RGO/SnIn$_4$S$_8$) composites with strong mineralization ability by a low-temperature co-precipitation method. The morphology, structure and photocatalytic activity of the RGO/SnIn$_4$S$_8$ composites were studied. The photocatalytic degradation kinetics, mineralization kinetics and degradation pathways of Rhodamine B (RhB) were systematically investigated under visible-light irradiation. Moreover, the possible photocatalytic mechanism of RGO/SnIn$_4$S$_8$ was provided.

2. Results and Discussion

2.1. Morphology Analysis

SEM images of RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite are shown in Figure 1. As shown in Figure 1a, the bare RGO is full of wrinkles, and the wrinkles form a curled and corrugated morphology. Pure SnIn$_4$S$_8$ possesses a network-like superstructure, which is constructed by numerous two-dimensional (2D) nanosheets with a thickness of about 10 nm. The assembly of the nanosheets produces abundant hierarchical pores at nanoscale (Figure 1b). In the case of the RGO/SnIn$_4$S$_8$ composite (Figure 1c), the nanosheets become obviously thinner, and the hierarchical pores between the nanosheets are smaller than those of pure SnIn$_4$S$_8$. 
2.2. XRD Analysis

Figure 2 shows the XRD patterns of bare RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite. It is obvious that bare RGO shows two characteristic diffraction peaks at 22.9° and 42.7°, corresponding to (002) and (100) planes of RGO [32]. The pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite have similar XRD profiles. The main diffraction peaks are observed at about 2θ = 19.0°, 28.4° and 50.1°, which can be indexed to the (202), (600) and (001) crystalline planes of tetragonal phase of SnIn$_4$S$_8$, respectively [33]. However, no RGO characteristic diffraction peaks are found in the XRD patterns of RGO/SnIn$_4$S$_8$ composite, which is possibly due to the limited amount and the destroyed regular stacks of RGO in the composite [34].
2.3. Raman Spectroscopy

It is well known that Raman spectroscopy is a powerful method for the characterization of sp² and sp³ hybridized carbon atoms in graphene to distinguish the ordered and disordered/defect structures. Therefore, Raman spectroscopy of GO, RGO, SnIn₄S₈ and RGO/SnIn₄S₈ composite was carried out (Figure 3). The two characteristic peaks of GO can be found at 1350 and 1585 cm⁻¹, corresponding to the D band (disorder peak) and G band (graphitic peak), respectively. The D band and G band of RGO located at 1344 and 1599 cm⁻¹, respectively. The shift of D band to around 1344 cm⁻¹ indicates the considerable increase in thickness of graphitic structure and size of the in-plane sp² domains [35]. In case of SnIn₄S₈, SnIn₄S₈ shows strong Raman characteristic peaks at 323 cm⁻¹. For the RGO/SnIn₄S₈ composite, we observed the characteristic bands of SnIn₄S₈ at 323 cm⁻¹ as well as the D band (ca. 1329 cm⁻¹) and G band (ca. 1602 cm⁻¹) of RGO, suggesting that the structure of RGO is maintained in the RGO/SnIn₄S₈ composite. The intensity ratio of D band to G band (I_D/I_G) can estimate the degree of disorder/defects in graphene. The I_D/I_G of GO is about 0.945, while the I_D/I_G of RGO and RGO/SnIn₄S₈ composite is about 1.118 and 1.146, respectively. The increase of I_D/I_G is attributed to the reduction and restoration of the sp² network of GO during the reduction process and the formation of more defects in RGO.

![Figure 3. Raman spectroscopy of GO, RGO, pure SnIn₄S₈, and RGO/SnIn₄S₈ composite.](image)

2.4. BET Surface Areas and Pore Structures

The Brunauer-Emmet-Teller (BET) surface area and pore structure play important roles in the photocatalytic performance of photocatalysts. Figure 4 shows the nitrogen adsorption-desorption isotherms and the corresponding pore size distribution curves of RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ composites with different RGO content. The nitrogen adsorption-desorption curves of these samples are type IV (Brunauer-Deming-Deming-Teller (BDDT) classification), indicating the presence of mesopores [36]. These isotherms exhibit H₃ hysteresis loops, suggesting that slit-like pores were formed by the aggregation of plate-like particles, which is consistent with the above SEM analysis. The results of BET surface area, pore volume, and average pore size of RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ are listed in Table 1. With the increase of RGO content in the composite samples, the specific surface area increases first and then decreases. When the content of RGO is 1% and 5%, the specific surface area is the largest (about 35 m²·g⁻¹) [37–39].
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...charge–carrier transport [40]. Moreover, the absorption edge of the RGO/SnIn$_4$S$_8$ composites shows a red-shift to a higher wavelength, which is probably attributed to the reduced reflection of light and the interfacial interaction between SnIn$_4$S$_8$ and RGO support to create a smooth charge–carrier transport [40].

2.5. Optical Properties

Figure 5 shows the UV-Visible diffuse reflectance spectroscopy of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites. Compared with pure SnIn$_4$S$_8$, the absorption of the RGO/SnIn$_4$S$_8$ composites obviously enhanced in ultraviolet (UV) and visible-light regions. Moreover, the absorption edge of the RGO/SnIn$_4$S$_8$ composites shows a red-shift to a higher wavelength, which is probably attributed to reduced reflection of light and the interfacial interaction between SnIn$_4$S$_8$ and RGO support to create a smooth charge–carrier transport [40].

Figure 5. (a) UV-Visible diffuse reflectance spectra and plots of $(a\nu)^2$ versus $\nu$ (inset) of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites with different RGO proportions; (b) the band gap can be changed with different RGO content in RGO/SnIn$_4$S$_8$ composites.

Table 1. Physical properties of reduced graphene oxide (RGO), pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites with different RGO content.

<table>
<thead>
<tr>
<th>Samples</th>
<th>$S_{\text{BET}}$ (m$^2$.g$^{-1}$)</th>
<th>Pore Volume (cm$^3$.g$^{-1}$)</th>
<th>Average Pore Size (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>RGO</td>
<td>134.31</td>
<td>0.029</td>
<td>3.402</td>
</tr>
<tr>
<td>SnIn$_4$S$_8$</td>
<td>23.35</td>
<td>0.11</td>
<td>19.067</td>
</tr>
<tr>
<td>1% RGO/SnIn$_4$S$_8$</td>
<td>35.02</td>
<td>0.175</td>
<td>20.015</td>
</tr>
<tr>
<td>5% RGO/SnIn$_4$S$_8$</td>
<td>35.29</td>
<td>0.159</td>
<td>18.094</td>
</tr>
<tr>
<td>10% RGO/SnIn$_4$S$_8$</td>
<td>23.48</td>
<td>0.109</td>
<td>18.628</td>
</tr>
</tbody>
</table>
The band gap energies ($E_g$) can be estimated from the following Kubelka–Munk equation:

$$(ahv)^n = k(hv - E_g)$$

where $a$ is the absorption coefficient, $k$ is a constant, $hv$ is the photonic energy, $E_g$ is the absorption band gap energy, $n$ is 2 and 1/2 for a direct and indirect band gap semiconductor, respectively. Plot of $(ahv)^2$ against $hv$ based on the direct transition is shown in inset of Figure 5. According to the inset of Figure 5, the $E_g$ of pure SnIn$_4$S$_8$, 1% RGO/SnIn$_4$S$_8$, 5% RGO/SnIn$_4$S$_8$ and 10% RGO/SnIn$_4$S$_8$ are estimated to be about 2.24, 2.12, 1.99 and 2.06 eV, respectively.

2.6. Mott-Schottky Analysis

The flat band potential ($E_{fb}$) of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite can be estimated from the Mott-Schottky equation:

$$
\frac{1}{C^2} = \frac{2}{\epsilon \varepsilon_0 N_d} (E - E_{fb} - \frac{k_B T}{e})
$$

where $C$ is the space charge capacitance, $\epsilon$ is the dielectric constant of the semiconductor, $\varepsilon_0$ is the permittivity of free space, $N_d$ is the donor density, $E$ is the applied potential, $E_{fb}$ is the flat-band potential, $k_B$ is Boltzmann’s constant ($1.38 \times 10^{-23}$ J K$^{-1}$), $T$ is the absolute temperature, and $e$ is the electronic charge. The positive slope of the linear part indicates that pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite show the characteristic of n-type semiconductor (Figure 6). The $E_{fb}$ value can be determined by extrapolating the linear part of the curve to $\frac{1}{C^2} = 0$, and the $E_{fb}$ values of SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite are $-0.614$ and $-0.294$ V versus the saturated calomel electrode (SCE), respectively. Supposing the difference between flat potential and conduction band can be negligible for n-type semiconductors [41], the $E_{fb}$ value is approximately equal to the $E_{CB}$ value. Compared with pure SnIn$_4$S$_8$, the $E_{CB}$ value of RGO/SnIn$_4$S$_8$ shifted to the positive direction, which could explain their enhanced photocatalytic activities. The electronic properties of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composite are listed in Table 2.

![Figure 6. Mott–Schottky curves of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites.](image)

**Table 2.** Electronic properties of SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$.

<table>
<thead>
<tr>
<th>Sample</th>
<th>$E_g$ (eV)</th>
<th>$E_{fb}$ (V vs. SCE)</th>
<th>$E_{fb} \approx E_{CB}$ (V vs. NHE)</th>
<th>$E_{VB}$ (V) *</th>
</tr>
</thead>
<tbody>
<tr>
<td>SnIn$_4$S$_8$</td>
<td>2.24</td>
<td>$-0.614$</td>
<td>$-0.372$</td>
<td>1.868</td>
</tr>
<tr>
<td>5% RGO/SnIn$_4$S$_8$</td>
<td>1.99</td>
<td>$-0.294$</td>
<td>$-0.052$</td>
<td>1.938</td>
</tr>
</tbody>
</table>

* Calculated according to: $E_{VB} = E_g + E_{CB}$. 
2.7. PL Emission Spectra

Figure 7 shows PL emission spectra of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites with different RGO proportions. As displayed in Figure 7, with increasing RGO content from 0% to 5%, the PL intensity decreased, but further increasing RGO content from 5% to 10% resulted in the increase of PL signals. It can be seen that 5% RGO/SnIn$_4$S$_8$ composites gives the weakest PL intensity than that of all other samples. The results indicated that proper RGO content is able to retard the recombination of photogenerated electron–hole pairs more effectively, but excess RGO can promote the recombination of photogenerated electron–hole pairs.

![Figure 7](image_url)

**Figure 7.** Photoluminescence (PL) spectra of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ with different RGO content.

2.8. Adsorption Kinetics

Adsorption kinetics of pollutant molecules on photocatalysts is a key factor that could have an important influence on subsequent photocatalytic reaction. The adsorption kinetics of RhB on RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites with different RGO content was investigated in the dark, and the results are shown in Figure 8a. The adsorption amount of RhB on RGO, SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ increases rapidly with time during the first 15 min, then it increases slowly from 15 to 40 min, and finally it does not change, indicating that the adsorption/desorption equilibrium is established in 40 min. The equilibrium adsorption capacity of RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites with different RGO content based on experiment ($q_{e,exp}$) is listed in Table 3.

![Figure 8](image_url)

**Figure 8.** (a) adsorption kinetics for RhB adsorption on RGO, pure SnIn$_4$S$_8$, and RGO/SnIn$_4$S$_8$ composites with different RGO content; (b) linear plot of $t/q$ vs. $t$ for RGO, pure SnIn$_4$S$_8$, and RGO/SnIn$_4$S$_8$ composites with different RGO content.
Table 3. Adsorption kinetic parameters for RhB adsorption on RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ composites with different RGO content.

<table>
<thead>
<tr>
<th>Sample</th>
<th>qₑₑₑ (mg g⁻¹)</th>
<th>Pseudo-First-Order</th>
<th></th>
<th>Pseudo-Second-Order</th>
<th></th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>qₑₑₑ (mg g⁻¹)</td>
<td>K₁ (min⁻¹)</td>
<td>R²</td>
<td>qₑₑₑ (mg g⁻¹)</td>
<td>K₂ (g mg⁻¹ min⁻¹)</td>
</tr>
<tr>
<td>RGO</td>
<td>4.805</td>
<td>0.453</td>
<td>0.323</td>
<td>0.518</td>
<td>4.826</td>
</tr>
<tr>
<td>SnIn₄S₈</td>
<td>2.037</td>
<td>0.719</td>
<td>0.0476</td>
<td>0.712</td>
<td>2.102</td>
</tr>
<tr>
<td>1% RGO/SnIn₄S₈</td>
<td>3.157</td>
<td>2.837</td>
<td>0.3945</td>
<td>0.985</td>
<td>3.244</td>
</tr>
<tr>
<td>5% RGO/SnIn₄S₈</td>
<td>4.181</td>
<td>1.835</td>
<td>0.0818</td>
<td>0.919</td>
<td>4.243</td>
</tr>
<tr>
<td>10% RGO/SnIn₄S₈</td>
<td>2.677</td>
<td>1.690</td>
<td>0.0923</td>
<td>0.883</td>
<td>2.789</td>
</tr>
</tbody>
</table>

The pseudo-first-order and pseudo-second-order equations were used to fit the adsorption kinetics data of RhB on RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ composites. The pseudo-first-order rate equation is expressed as

\[
\ln (qₑₑₑ - qₜ) = -K₁t + \ln qₑₑₑ
\]

where \(qₜ\) and \(qₑₑₑ\) are the amounts of RhB adsorbed on photocatalysts at adsorption equilibrium and any time \(t\), respectively (mg g⁻¹); \(K₁\) is adsorption rate constant (min⁻¹). The \(K₁\), correlation coefficients \((R²)\) and calculated \(qₑₑₑ\) values established from pseudo-first-order equation are depicted in Table 3. The \(R²\) values are relatively low, and the calculated \(qₑₑₑ\) value is far from the experimental value \((qₑₑₑₑₑₑ)\), indicating that the adsorption dynamics of RhB on RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ composites do not follow the pseudo-first-order kinetic model.

The linear form of pseudo-second-order model is expressed as followed:

\[
\frac{t}{qₜ} = \frac{t}{qₑₑₑ} + \frac{1}{K₂qₑₑₑ²}
\]

where \(qₜ\) and \(qₑₑₑ\) is the amount of adsorbate at any time \(t\) and adsorption equilibrium (mg g⁻¹), and \(K₂\) is the constant rate of pseudo-second-order adsorption (g mg⁻¹ min⁻¹). The regression curve of \(t/qₜ\) versus \(t\) was rather linear (Figure 8b), and all parameters determined from pseudo-second-order model are also summarized in Table 3. The \(R²\) values are close to 1, and the calculated \(qₑₑₑ\) \((qₑₑₑₑₑₑ)\) from the pseudo-second-order model is very close to the experimental value, suggesting that RhB adsorption on RGO, pure SnIn₄S₈ and RGO/SnIn₄S₈ composites followed the pseudo-second-order model with an important chemisorption process.

2.9. Photocatalytic Activities

2.9.1. The Temporal Change of UV-Visible Spectra during the Photocatalytic Degradation

Figure 9 shows the UV-Visible spectral changes during the photocatalytic degradation of RhB under visible-light irradiation. As the reaction proceeds, the maximum absorption wavelength of RhB at 554 nm disappear quickly, and there are obvious hypsochromic shifts in the maximum absorption peak position, which shifts from 554 to 510 nm [42]. Moreover, the absorption intensity decreases. The inset shows the maximum absorption wavelength as a function of reaction time. During the early stage of photocatalytic degradation process, the peak positions did not change obviously because of the relatively high concentration of RhB and the low concentration of intermediate products. With a further degradation of RhB and the formation of abundant N-deethylated intermediate products, the blue-shift phenomenon became clear.
with increasing RGO content from 0% to 5%. When the percent of RGO reaches 5%, RGO/SnIn$_4$S$_8$ composites exhibit remarkably enhanced photocatalytic activity of 5% RGO/SnIn$_4$S$_8$. Due to the demands of both the charge transfer and light harvesting, the photocatalytic activity of RGO/SnIn$_4$S$_8$ composites increases with increasing RGO content from 0% to 5%. When the percent of RGO reaches 5%, RGO/SnIn$_4$S$_8$ composites exhibit the highest photocatalytic activity of 5% RGO/SnIn$_4$S$_8$. One possible reason is that an appropriate amount of RGO is beneficial for the generation and transfer of photo-generated electrons and holes at heterojunction interfaces, while excessive RGO could shield SnIn$_4$S$_8$ from light as well as promote electron–hole recombination [43].

2.9.2. Adsorption and Photocatalytic Degradation of RhB

In order to separate the contribution of adsorption and degradation in the experiment, the adsorption process in the dark and photocatalytic degradation of RhB over RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites under visible-light irradiation were carried out (Figure 10a). In the absence of a catalyst, the concentration change of RhB solution is very slight (around 6% during 70 min exposure), indicating that the self-degradation under visible-light irradiation can be neglected. In the presence of RGO, about 90% of RhB was adsorbed by RGO before the photodegradation, indicating that RGO is an excellent adsorbent. By discounting the adsorption contribution, the photocatalytic degradation of RhB over RGO, pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites under visible-light irradiation was shown in Figure 10b. In the presence of pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ composites, RhB photodegradation is remarkably enhanced. The photocatalytic activity of RGO/SnIn$_4$S$_8$ composite is much higher than that of pure SnIn$_4$S$_8$ and RGO, and the photocatalytic activity of RGO/SnIn$_4$S$_8$ composites is greatly influenced by the RGO content. The photocatalytic activity of RGO/SnIn$_4$S$_8$ composite increases with increasing RGO content from 0% to 5%. When the percent of RGO reaches 5%, RGO/SnIn$_4$S$_8$ exhibits the highest photocatalytic activity, giving rise to the almost complete removal of RhB within 70 min under visible-light irradiation. However, as the proportion of RGO further increases, the degradation efficiency decreases gradually, and the degradation of RhB needs much longer time.

Figure 9. UV-Visible spectral changes of RhB solution in the presence of 5% RGO/SnIn$_4$S$_8$ as a function of reaction time. Inset: maximum absorption wavelength shifts as a function of reaction time.
and its intermediate products were analyzed using HPLC-MS (Figure 12). According to the

where

It can be seen from Figure 11 that TOC removal efficiency of RhB solution increases with increasing
time.

removal efficiency was calculated according to the following equation:

\[
\text{TOC removal efficiency} = \frac{\text{TOC}_0 - \text{TOC}_t}{\text{TOC}_0} \times 100\%
\]

where \( \text{TOC}_0 \) represents the initial TOC value of RhB solution, and \( \text{TOC}_t \) is the TOC value at any time \( t \).

It can be seen from Figure 11 that TOC removal efficiency of RhB solution increases with increasing
visible-light irradiation time, and the TOC removal efficiency reaches 73.17% after exposure to
visible-light irradiation for 160 min, indicating that the most of RhB and its \( N \)-deethylated intermediate
products were decomposed into inorganic species.

To further understand the photocatalytic degradation and mineralization pathways of RhB, RhB
and its intermediate products were analyzed using HPLC-MS (Figure 12). According to the \( m/z \)
values of the intermediate products and the structure of RhB, we have inferred the pathways of
photocatalytic degradation and mineralization (Figure 13). The mass peaks at \( m/z \) 443, 413, 399, 346,
and 328 correspond to RhB and its N-deethyalted intermediates (N,N-diethyl-N'-ethylrhodamine (DER), N,N-diethylrhodamine (DR), N-ethylrhodamine (ER), and rhodamine (R)). As further oxidation proceeded, adipic acid, phthalic acid, isophthalic acid, and terephthalic acid were generated. Finally, these small molecules were mineralized into CO2 and H2O, which can be proved by TOC results.

Figure 12. Mass spectrum view of RhB and its intermediates that appeared in the photodegradation process.

Figure 13. The proposed degradation pathways of RhB in RGO/SnIn4S8 suspension under visible-light irradiation.

2.11. Photocatalytic Mechanism

It is very important to examine main reactive species (such as h+, \( \cdot \)OH and \( \cdot \)O2− radicals) in photocatalytic reaction for understanding the photocatalytic mechanism of RGO/SnIn4S8 under visible-light irradiation. Figure 14 shows the degradation efficiency of RhB over 5% RGO/SnIn4S8 in the presence of isopropanol (IPA, \( \cdot \)OH quencher), triethanolamine (TEOA, h+ quencher) and benzoquinone (BQ, \( \cdot \)O2− quencher). When no quenchers were added, the degradation efficiency of RhB is 98.72%.
When TEOA and BQ scavengers were added, the RhB degradation efficiency was significantly reduced to 6.57% and 33.40%, respectively. In the case of adding an IPA scavenger, the degradation efficiency of RhB decreased to 68.30%. Therefore, it can be concluded that h+, O2− and -OH are the main active species which play crucial roles in the degradation of RhB, and the order of affecting degradation efficiency of RhB follows that of h+ > O2− > -OH.

Based on the experiment results and the reported literature [44–46], the generation and transfer of the photogenerated electrons and holes in RGO/SnIn4S8 composites are illustrated in Scheme 1. As shown in Scheme 1, under visible-light irradiation, the electrons (e−) excited in valence band (VB) would transfer to the conduction band (CB) of SnIn4S8, whereas the holes (h+) would generate in the VB of SnIn4S8. The photo-generated e− in the CB of the SnIn4S8 can be injected into RGO, therefore hindering the recombination process of the e−-h+ pairs. The photo-generated e− in RGO could react with adsorbed O2 to form -O2− radicals. Most of -O2− radicals play an important role in the degradation of RhB molecules, others could further react with H2O to generate hydroxyl radicals (-OH). The h+ in the VB of SnIn4S8 are decisive to oxidize RhB molecules adsorbed on the surface of RGO/SnIn4S8 composites, meanwhile, -O2− and -OH radicals are beneficial to the degradation of RhB. The photocatalytic process of RhB under visible-light irradiation, among with 1RhB* and 3RhB* represent the ΩST and the triplet respectively [47,48]. The equations are as follows:

\[ e^- + RGO \rightarrow RGO(e^-) \]  \hspace{1cm} (1)
\[ RGO(e^-) + O_2 \rightarrow \cdot O_2^- \]  \hspace{1cm} (2)
\[ \cdot O_2^- + H_2O \rightarrow \cdot O_2H + OH^- \]  \hspace{1cm} (3)
\[ RhB^+ + \cdot O_2 \rightarrow RhBO_2 \rightarrow \text{decomposition products} \]  \hspace{1cm} (4)
\[ RhB^+ + HO_2 \rightarrow \text{decomposition products} \]  \hspace{1cm} (5)

Equation (2) is followed by Reaction (7) and the following sequence:

\[ RhB + h\nu(\text{vis}) \rightarrow 1RhB^* \text{ or } 3RhB^3 \]  \hspace{1cm} (6)
\[ 1RhB^* \text{ or } 3RhB^* + RGO/SnIn_4S_8 \rightarrow RhB^+ + \cdot SnIn_4S_8(h^+ + e^-) \]  \hspace{1cm} (7)
\[ RhB^+ + \text{decomposition products} \]  \hspace{1cm} (8)
\[ RhB^+ + OH^- \rightarrow RhB + \cdot OH \]  \hspace{1cm} (9)
\[ RhB + \cdot OH \rightarrow \text{decomposition products} \]  \hspace{1cm} (10)
2.12. Regeneration and Reuse of Spent RGO/SnIn₄S₈ Composites

The stability of RGO/SnIn₄S₈ composites has also been studied to evaluate its economic value and practical application. As shown in Figure 15, after four consecutive photocatalytic degradation-regeneration cycles, the photocatalytic performance of the regenerated 5% RGO/SnIn₄S₈ composites is similar to that of their fresh counterparts, indicating that 5% RGO/SnIn₄S₈ composites exhibit high stability, and could be used repeatedly.

![Scheme 1. A schematic illustration for the photocatalytic mechanism of RhB on reduced graphene oxide (RGO)/SnIn₄S₈ composites under visible-light irradiation.](image)

**Figure 15.** Regeneration and reuse of 5% RGO/SnIn₄S₈ composites.

3. Experimental Section

3.1. Materials and Chemicals

Thioacetamide (TAA) was attained from Tianjin Chemical Reagent Plant (Tianjin, China). Tin (IV) chloride pentahydrate (SnCl₄·5H₂O) and indium (III) chloride tetrahydrate (InCl₃·4H₂O) were received from Aladdin Chemistry Co. Ltd. (Shanghai, China). Graphite powder, 80% hydrazine hydrate, anhydrous ethanol, sodium sulfate (Na₂SO₄) and iso-propyl alcohol (IPA) were obtained from Shantou Xilong Chemical Co., Ltd. (Shantou, China). p-Benzoinone (BQ) was supplied by Shanghai Crystal Pure Reagent Co., Ltd. (Shanghai, China). Triethanolamine (TEOA) was acquired from Shanghai Crystal Pure Reagent Co., Ltd. (Shanghai, China).
Pure Reagent Co., Ltd. (Shanghai, China). Triethanolamine (TEOA) was acquired from Shanghai Chemical Reagent Co., Ltd. (Shanghai, China). Rhodamine B (RhB) was provided by Shanghai Chemical Technology Co., Ltd. (Shanghai, China). All the reagents were of analytical grade and used without further purification. Deionized water was further purified using a Milli-Q water system (Bedford, MD, USA).

3.2. The Low-Temperature Co-Precipitation Synthesis of Pure SnIn$_4$S$_8$ and RGO/SnIn$_4$S$_8$ Composite

Graphene oxide (GO) was prepared by the modified Hummers method [49], and then GO was reduced to RGO by 80% hydrazine hydrate. To synthesize RGO/SnIn$_4$S$_8$ composites with different amount of RGO, a simple low-temperature co-precipitation method was used. In a typical procedure, 0.521 g of SnCl$_4$·5H$_2$O (2.0 mmol) and 1.769 g of InCl$_3$·4H$_2$O (8.0 mmol) were dissolved in 50 mL of anhydrous ethanol under magnetic stirring, and then 1.127 g of TAA (15 mmol) was added to the above solution. The mixture solution was stirred for about 25 min until the solution became transparent, then a certain amount of RGO was added to the mixture solution and followed by ultrasonication for 20 min to form a transparent solution. The above solution was transferred to a 150 mL three flask with a condensing unit and maintained at bath temperature of 80 °C for 5 h under continuous stirring, then cooled to room temperature naturally. The obtained yellow precipitate was filtered and washed with distilled water and absolute ethanol several times, and dried at 80 °C in vacuum for 12 h. The samples with different molar ratio of C to Sn were designated as pure SnIn$_4$S$_8$, 1% RGO/SnIn$_4$S$_8$, 5% RGO/SnIn$_4$S$_8$ and 10% RGO/SnIn$_4$S$_8$, respectively.

3.3. Characterization

U-3900H scan UV-Vis spectrophotometer (Hitachi, Tokyo, Japan) equipped with a Labsphere diffuse reflectance accessory was used to obtain the reflectance spectra of the photocatalysts over a range of 200–800 nm. Morphologies of the photocatalysts were analyzed by scanning electron microscopy (SEM) instrument (Shimadzu, Kyoto, Japan). BET surface areas and pore structures were measured using a GEMINI VII 2390 surface area and porosity analyzer (Micromeritics, Atlanta, GA, USA). X-ray diffraction (XRD) patterns of products were obtained by using an automatic X-ray diffractometer (XRD, Rigaku D/max 2200PC, Karlsruhe, Germany) with Cu Kα radiation. Raman spectra of samples were obtained using a LabRAM HR spectrophotometer (Jobin Yvon, Paris, France) with an excitation wavelength of 632.8 nm. The photoluminescence (PL) were measured using F-7000 fluorescence spectrophotometer (Hitachi, Tokyo, Japan) with an excitation wavelength of 474 nm. The total organic carbon (TOC) of the samples was analyzed by using an Apollo 9000 TOC analyzer (Terkmar-Dohrmann, Atlanta, GA, USA). The intermediate products were analyzed by using LCQ-Deca-XP high performance liquid chromatography-tandem mass spectrometry (HPLC-MS, Thermo Finnigan, Atlanta, GA, USA).

3.4. Electrochemical Measurement

The flat-band potential of 5% RGO/SnIn$_4$S$_8$ was determined by extrapolating the Mott-Schottky plots. Mott-Schottky plots were performed on an electrochemical workstation (CHI660C, Shanghai Chenhua Instrument Corporation, Beijing, China) with a standard three-electrode cell in the potential range between −1.0 and 1.0 V with scan frequency of 1000 Hz and 0.025 V sinus amplitude. This three-electrode cell was consisted of a saturated calomel electrode (SCE) as reference electrode, a graphite electrode as counter electrode, RGO/SnIn$_4$S$_8$-modified indium tin oxide (ITO) conducting glass as the working electrode, and 0.5 mol·L$^{-1}$ Na$_2$SO$_4$ as the electrolyte.

3.5. Adsorption Dynamics in the Dark

In addition, 0.03 g of pure SnIn$_4$S$_8$, 1% RGO/SnIn$_4$S$_8$, 5% RGO/SnIn$_4$S$_8$, 10% RGO/SnIn$_4$S$_8$, or RGO was mixed with 160 mL of 10 mg·L$^{-1}$ RhB solution in a conical flask, respectively. The conical flasks were shaken at 20 °C in the dark. In addition, 3 mL suspension was sampled at different time
intervals, and filtered immediately to remove the photocatalysts. The concentration of RhB in the filtrate was measured by HPLC with detection wavelength of 553.5 nm. The adsorbed amount at any time \( t \) \((q_t)\) is calculated as follows:

\[
q_t = \frac{(C_0 - C_t)V}{m}
\]

where \( C_0 \) (mg L\(^{-1}\)) is the initial RhB concentration, \( C_t \) (mg L\(^{-1}\)) is the RhB concentration at time \( t \), \( V \) (mL) is the volume of RhB solution, and \( m \) (g) is the mass of the photocatalysts.

3.6. Visible-Light Photocatalytic Activity Measurement

A 300 W xenon lamp (PLS-SXE300, Beijing Trusttech Co., Ltd., Beijing, China) with a 400 nm cut-off filter (400 nm < \( \lambda \) < 780 nm) was used as the source of visible light. The photocatalytic activities of pure SnIn\(_4\)S\(_8\) and RGO/SnIn\(_4\)S\(_8\) were evaluated by the degradation of RhB under visible-light irradiation. Typically, 30 mg of pure SnIn\(_4\)S\(_8\) or RGO/SnIn\(_4\)S\(_8\) composite was added to 160 mL of RhB solution (10 mg L\(^{-1}\)), respectively. Before irradiation, the suspensions were magnetically stirred in the dark for 40 min in order to establish an adsorption-desorption equilibrium. Under continuous stirring, the mixed solution was irradiated by visible light. The reaction suspension was sampled at intervals of 10 min. After immediate filtration, the clear solution was analyzed using a 754 UV-Vis spectrometer at a wavelength of 553.5 nm, which is the maximum absorption wavelength of RhB. The concentration of RhB was estimated by a calibration curve. The intermediate products were analyzed by using HPLC-MS.

3.7. Regeneration and Reuse of Spent RGO/SnIn\(_4\)S\(_8\) Composite Catalyst

In order to evaluate the stability and reusability of RGO/SnIn\(_4\)S\(_8\), consecutive photocatalytic degradation-regeneration cycles were repeated four times. The spent RGO/SnIn\(_4\)S\(_8\) composite was recovered from the mixture solution by filtration and washed with plenty of water (0.1 g RGO/SnIn\(_4\)S\(_8\) composite with 400 mL water), then dried at 60 °C for 4 h. The regenerated RGO/SnIn\(_4\)S\(_8\) composite was used for subsequent cycles of photocatalytic degradation under similar reaction conditions as carried out with fresh catalyst.

4. Conclusions

We successfully prepared hierarchically porous reduced graphene oxide/SnIn\(_4\)S\(_8\) (RGO/SnIn\(_4\)S\(_8\)) composites with visible-light response and strong mineralization ability by a facile low-temperature co-precipitation method. Compared with pure SnIn\(_4\)S\(_8\), RGO/SnIn\(_4\)S\(_8\) composite exhibits enhanced absorption in UV and visible-light range. The RGO content was optimized, and the optimal content of RGO nanosheets is 5%. The optimal 5% RGO/SnIn\(_4\)S\(_8\) possesses the best photocatalytic degradation efficiency and mineralization performance with complete degradation of Rhodamine B within 70 min and 73.17% mineralization yield within 160 min under visible-light irradiation, which is much higher than that of pure SnIn\(_4\)S\(_8\). The main reactive species that affect degradation and mineralization efficiency of RhB follow the order of \( h^+ > -O_2^- > -OH \). The intermediate products of RhB degradation were analyzed, and the possible degradation pathways and detailed degradation mechanism were proposed. Moreover, 5% RGO/SnIn\(_4\)S\(_8\) exhibits excellent reusability and stability without obvious decrease of photocatalytic activity.

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Author Contributions: Fang Deng conceived and designed the experiments; Xule Pei performed the experiments; Fang Deng and Xule Pei analyzed the data; Key Laboratory of Jiangxi Province for Persistent Pollutants Control and Resources Recycle, Nanchang Hangkong University contributed reagents/materials/analysis tools; All the authors discussed the results, analyzed data and wrote this paper.

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